

Shrinking the footprints of polarization splitter-rotators with highly-birefringent molybdenum disulfide waveguides

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Abstract—A polarization splitter-rotator (PSR) based on an asymmetric directional coupler (ADC) with molybdenum disulfide (MoS₂) waveguides is proposed. Owing to the high in-plane refractive index and the extreme birefringence of MoS₂, an ultra-small cross-polarization coupling length of 6.0 μm can be achieved. At the working wavelength of 1.55 μm , this ADC-type PSR exhibits a high TM₀-to-TE₀ polarization conversion efficiency of 96.97% and a low conversion loss of 0.38 dB. Additionally, the TE₀-to-TE₀ insertion loss and cross-talk are remarkably low, measuring at 0.006 dB and -31.53 dB, respectively. We verify through simulations that the extremely high birefringence of MoS₂ is a necessity for achieving simple and ultra-compact ADC-PSR with straight waveguide geometries. This exceptional impact of extreme birefringence of MoS₂ indicates a unique and promising prospect for developing high-performance nanophotonic components based on the van der Waals on insulator (vdW-OI) configuration.

Keywords—integrated optics, polarization management, optical anisotropy, van der Waals materials, modal birefringence

I. INTRODUCTION

Polarization splitters [1-3] and polarization rotators [4] can realize the separation and inter-conversion of orthogonally polarized transverse electric (TE) and transverse magnetic (TM) waveguide modes, alleviate the polarization dependence of the high refractive index contrast silicon-on-insulator (SOI) photonic platform, [5, 6] thus are indispensable components in integrated optical circuits based on polarization-diversity schemes.[7, 8] Compared with discrete polarization splitters and rotators, compact polarization splitter-rotator (PSR) is much more desirable for achieving high-density integration in terms of reliability and stability. [9] In recent years, great efforts have been devoted to achieving compact PSRs through innovative structure designs. Typical examples include devices based on asymmetric directional couplers (ADC), [10-14] tapers, [15-19] multi-mode interference (MMI) couplers, [20] subwavelength gratings (SWGs), [21-23] metamaterials, [24, 25] and two-dimensional material composite waveguides, [26] etc. However, the PSRs based on tapers or MMI structures are challenging to reduce in footprint to below

tens of micrometers. [19] Other novel designs can achieve a size reduction to around 10 μm , at the cost of some other shortcomings, such as the manufacturing difficulty associated with the structural intricacy of SWGs, [27] the extra transmission loss induced by a hybrid plasmonic waveguide (HPW), [9] and the experimental challenge caused by embedding graphene into waveguides. [26] Therefore, an ultra-compact PSR design with a simple structure yet high performance is still urgently needed.

ADC composed of two parallel straight waveguides (SW) is a promising structure to realize compact and uncomplicated PSRs on the SOI platform. [28] However, the maximum modal birefringence of silicon waveguide on SOI is limited to 0.7 with a waveguide height of 250 nm. This fundamental restriction imposes a constraint on the compact footprint achievable for Si-based straight waveguides ADC-PSRs, confining their size to the magnitude of tens of micrometers. [11] Large optical birefringence of the waveguide material is conducive to achieving significant phase mismatch between different guided modes (modal birefringence), [27] thereby would facilitate the further miniaturization of SW-based ADC-PSRs. [28] Thanks to their layered structures, transition metal dichalcogenides (TMDs) exhibit large optical anisotropies. [29-36] Especially, molybdenum disulfide (MoS₂) with a high in-plane refractive index (over 4) [37-40] and low absorption in the communication band [41] shows a giant birefringence over 1.4. [29, 34, 38] Therefore, by incorporating MoS₂ into the design of PSR, its high refractive index would enhance the optical confinement and its extreme birefringence would improve the coupling efficiency between the two parallel waveguides, enabling a significant reduction in component footprint.

In this paper, we propose a concept of van der Waals on insulator (vdW-OI) configuration, in which two-dimensional (2D) materials are integrated into a layered stack with an insulating material, typically silicon dioxide (SiO₂). By utilizing this configuration, we design an ultra-compact and high-performance PSR based on ADC consisting of two parallel straight MoS₂ waveguides. Initially, we unveil the

remarkable modal birefringence between the TE_0 and TM_0 modes of the MoS_2 waveguide by precisely calculating the effective refractive indices at the wavelength $\lambda = 1.55 \mu m$. Then, we demonstrate that the PSR can realize polarization separation and rotation with an ultra-small footprint. To the best of our knowledge, this is the simplest PSR design that can achieve high polarization conversion efficiency and ultra-short coupling length simultaneously. Through further simulations, we confirm the indispensability of the extremely birefringent MoS_2 waveguides in the realization of a simplistic yet ultra-compact PSR.

II. METHODS

Optical simulations are conducted with the numerical software. MoS_2 is considered lossless and the imaginary parts of its refractive indices are set to zero, while the real parts are 4.07 and 2.7 for the in- and out-of-plane directions, respectively [34]. Other materials are selected from the material library of the simulation software.

III. RESULTS AND DISCUSSION

The proposed PSR is sketched in Fig. 1(a). It consists of an ADC with two parallel straight waveguides, an S-bend connected to the thru port, and the air upper cladding. The inset of Fig. 1(a) shows the layer structure of MoS_2 leading to its significant optical anisotropy. [42] To determine the cross-sectional sizes of the straight waveguides, we analyze the modal dispersions of MoS_2 waveguide using the mode solver integrated with the Finite-Difference Time-Domain (FDTD) software. [43] Fig. 1(b) illustrates the variation of the effective refractive indices (n_{eff}) of the first three guided modes with the increasing width of MoS_2 waveguide. Significantly, an extreme modal birefringence can be observed between the TM_0 and TE_0 modes (over 1.6), thereby offering a method for polarization separation. By adjusting the widths (W_1 and W_2) of these two straight waveguides, it becomes possible to achieve a phase-matching condition wherein the n_{eff} of the TM_0 mode in the thru waveguide matches that of the TE_0 mode in the cross waveguide. ($n_{eff}^{1, TM} = n_{eff}^{2, TE}$). To fulfill this condition, we employ structural parameters of $W_1 = 455 \text{ nm}$ and $W_2 = 234 \text{ nm}$, thereby ensuring a modal birefringence larger than 1.4 in the thru waveguide. Consequently, the n_{eff} of TE_0 mode in the thru waveguide significantly deviates from that of any guided mode in the cross waveguide. Based on the coupled mode theory, this configuration guarantees uncoupled propagation for the TE_0 mode in the thru waveguide, [11, 44] while effectively facilitating the coupling of the TM_0 input mode to the adjacent cross waveguide through the ADC. As a result, simultaneous polarization separation and rotation are accomplished.

To ensure comparability with silicon-based straight waveguides ADC-PSR, [11] we maintain the same gap width between the two straight waveguides ($W_g = 150 \text{ nm}$). By utilizing 3D numerical FDTD simulations, we optimize the coupling length (L_c) based on the transmission performance of cross port and thru port. Fig. 2(a) illustrates the transmission coefficient as a function of L_c . Within the range of 5.6 to $6.8 \mu m$, the PSR demonstrates a transmission efficiency higher than -0.4 dB for TM_0 to TE_0 . Notably, at the L_c of $6.0 \mu m$, the transmission efficiency of TM_0 to TE_0 achieves a peak value of -0.35 dB , while the transmission efficiency of TM_0 to TM_0 is -15.98 dB . With the optimized L_c , we perform simulations to analyze the optical power

distribution of TM_0 and TE_0 polarized light along the waveguides, as shown in Fig. 2(b) and (c). For the TM_0 input mode [in Fig. 2(b)], the optical power in the thru waveguide gradually couples into the cross waveguide along the propagation direction, accompanied by conversion from TM_0 to TE_0 mode. The electric field distribution at the corresponding position in Fig. 2(d-f) further confirms the polarization conversion. Conversely, due to the significant modal birefringence of MoS_2 waveguide, a substantial phase mismatch exists between TE_0 mode in the thru waveguide and TE_0 mode in the cross waveguide. Consequently, the TE_0 input mode remains confined within the thru waveguide without any cross-coupling [Fig. 2(c)]. Thus, the simulation results validate the polarization separation and conversion functionalities of the proposed PSR.

To evaluate the performance of the designed PSR, we conduct 3D-FDTD simulations and calculate a series of key performance indicators. For the TM_0 input mode, a key parameter is the polarization conversion efficiency (*PCE*), defined as: [8]

$$PCE(\%) = T_{TE\text{-cross}} / (T_{TE\text{-cross}} + T_{TM\text{-thru}}) \times 100\% \quad (1)$$

where $T_{TE\text{-cross}}$ is the transmission of TE_0 in the cross port and $T_{TM\text{-thru}}$ is the transmission of TM_0 in the thru port. [26]

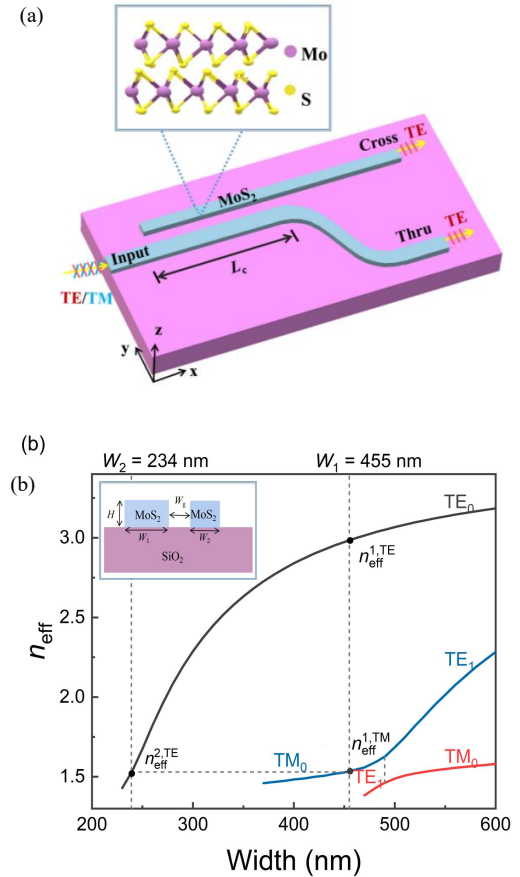


Fig. 1. Schematic diagram of the proposed PSR and modal characteristics of MoS_2 waveguide. (a) Layout of the MoS_2 -based PSR, including two parallel straight waveguides an S-bend connected to the thru port, and the air upper cladding. L_c : the length of ADC. Inset: the layer structure of MoS_2 . (b) Effective refractive indices (n_{eff}) of the first three guided modes in MoS_2 waveguide with varying width. $H = 220 \text{ nm}$, $\lambda = 1.55 \mu m$. Inset: cross-section of the coupling region. W_1 : width of thru waveguide. W_2 : width of cross waveguide. W_g : width of the gap between two parallel coupled straight waveguides.

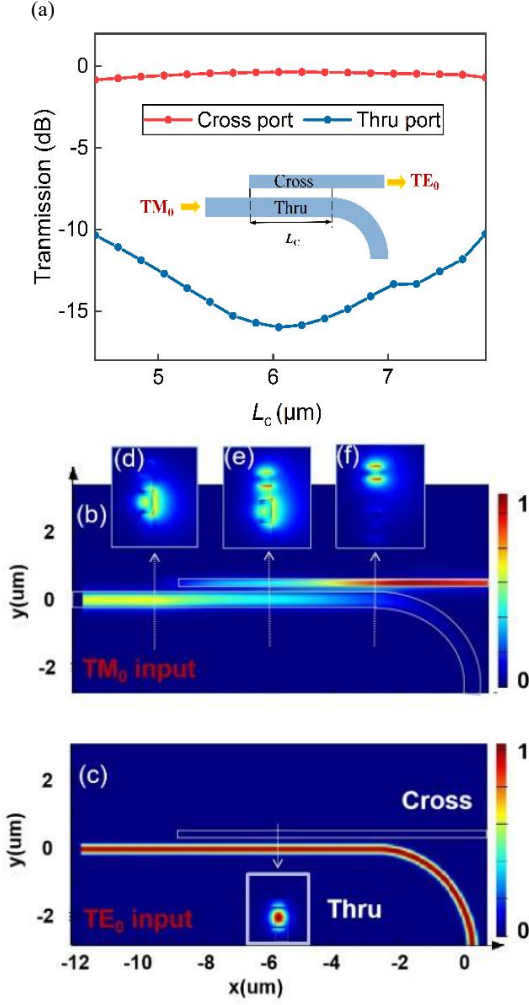


Fig. 2. Transmission characteristics of MoS₂-based PSR with different L_c and the optical power distribution in the PSR with $W_1 = 455$ nm, $W_2 = 234$ nm, $H = 220$ nm, and $\lambda = 1.55$ μ m. (a) For TM₀ input mode, the transmission performance of the device varies with L_c . Inset: the simulation model. Optical power distribution in the designed PSR for (b) TM₀ input; (c) TE₀ input, inset: normalized electric field distribution with TE₀ as input. (d-f) TM₀ input, normalized electric field distributions at corresponding positions (indicated by arrows) along the PSR.

In addition, we also characterize the polarization conversion loss (PCL) and the crosstalk (CT), which are defined as:

$$PCL \text{ (dB)} = -10 \log_{10} \frac{P_{TE}^C}{P_{TM}^I}, \quad (2)$$

$$CT \text{ (dB)} = 10 \log_{10} \frac{P_{TM}^T}{P_{TE}^C}. \quad (3)$$

where refers to the power of the x polarization mode (TE or TM) at the y port (I: input port, T: thru port, C: cross port, and R: reflection port). [25] For the TE₀ input mode, we calculate CT , insertion loss (IL), and reflection loss (RL) instead, which are defined as: [25]

$$CT \text{ (dB)} = 10 \log_{10} \frac{P_{TM}^C}{P_{TE}^I}, \quad (4)$$

$$IL \text{ (dB)} = -10 \log_{10} \frac{P_{TE}^T}{P_{TE}^I}, \quad (5)$$

$$RL \text{ (dB)} = 10 \log_{10} \frac{P_{TE}^R}{P_{TE}^I}. \quad (6)$$

where the definition of is identical to that of the input TM₀ mode.

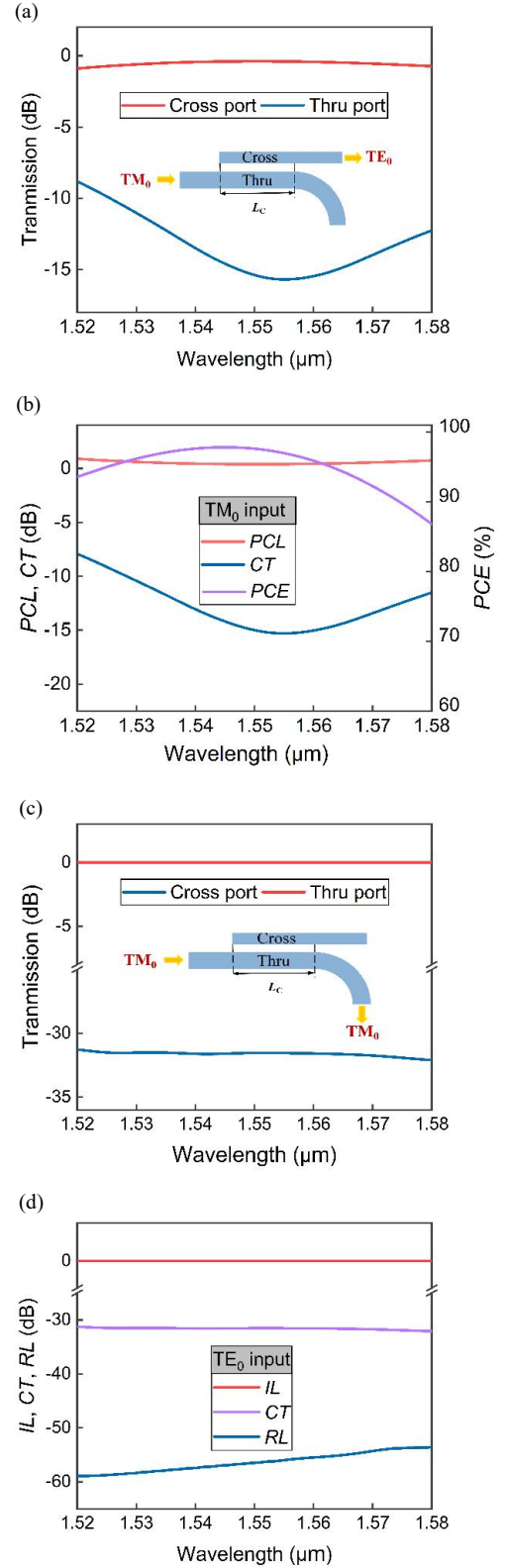


Fig. 3. Wavelength dependence of the key performance indicators (Transmission, PCL , CT , PCE , IL and RL) of the PSR. (a, b) TM₀ input and (c, d) TE₀ input. The simulation models are displayed in the insets respectively

Fig. 3 depicts the wavelength-dependent transmission performances of the designed PSR when TM₀ and TE₀ modes are used as inputs, respectively. With TM₀ as the input mode [Fig. 3(a)], the optical power output is mainly from the cross port, exhibiting wavelength dependence.

Specifically, the thru-port transmission reaches a minimum value of approximately -15.69 dB at $\lambda = 1.55 \mu\text{m}$, whereas the cross-port transmission reaches a maximum value of about -0.38 dB. Simultaneously, the *PCE* of TM_0 to TE_0 at the cross port achieves 96.97% [Fig. 3(b)], with the corresponding *CT* and *PCL* are -15.3 dB and 0.38 dB, respectively. As the working wavelength deviates from $1.55 \mu\text{m}$, the *PCE* gradually decreases, meaning that TM_0 mode is sensitive to variations in wavelength. On the other hand, with TE_0 as the input mode [Fig. 3(c)], the optical power output primarily originates from the thru port and almost no light transmits into the cross waveguide, showing a wavelength-insensitive low *CT* of below -31 dB [as shown in Fig. 3(d)]. This merit can be attributed to the extreme birefringence of MoS_2 , which induces a significant phase mismatch between TE_0 mode in the thru waveguide and TE_0 mode in the cross waveguide. Furthermore, Fig. 3(d) also demonstrates that the TE_0 input mode has an exceptionally low *IL* of 0.006 dB and *RL* below -53 dB.

To explore the influence of MoS_2 birefringence on the coupling length and the key performance indicators of the PSR, we performed two sets of simulations, varying the out-

of-plane refractive index of MoS_2 (n_{\perp, MoS_2}) while fixing $W_1 = 455 \text{ nm}$ and $n_{\text{eff}}^{1, \text{TM}} = 1.53$, respectively. As shown in Fig. 4(a), the coupling length exhibits a nonlinear increase with increasing n_{\perp, MoS_2} (the variations of modal birefringence are shown in the inset). Particularly, at $W_1 = 455 \text{ nm}$, L_c exponentially increases from $6 \mu\text{m}$ ($n_{\perp, \text{MoS}_2} = 2.7$) to $49.4 \mu\text{m}$ ($n_{\perp, \text{MoS}_2} = 3.9$), where $n_{\perp, \text{MoS}_2} = 2.7$ is the genuine out-of-plane refractive index of MoS_2 . This arises from the enhanced field confinement capability of the input waveguide (as demonstrated in Fig. 4(b, c)), resulting from the increased value of $n_{\text{eff}}^{1, \text{TM}}$. Consequently, there is a reduction in modal field overlap between the coupled waveguides, leading to a weakened cross-coupling effect. [45] However, when $n_{\text{eff}}^{1, \text{TM}} = 1.53$, L_c varies non-monotonically. This intricate behaviour arises from the interplay of two factors influencing the cross-coupling strength. Firstly, the decrease in optical birefringence diminishes the cross-coupling owing to alterations in the polarization fraction of TM_0 and TE_0 in the eigenmodes. Secondly, the reduction of W_1 increases the modal field overlap, thereby reinforcing the cross-coupling effect. In general, the reduction of birefringence exerts a more pronounced influence on cross-coupling, resulting in an elongation of the coupling length. However, when W_1 is small enough ($< 300 \text{ nm}$), a greater portion of the modal fields extends beyond the waveguide boundaries (e. g. in Fig. 4(d), $W_1 = 267 \text{ nm}$), thereby amplifying the modal field overlap. It is the delicate balance between these opposing factors that give rise to the non-monotonical behavior observed in L_c illustrated in Fig. 4(a).

The key performance indicators of the PSR are also birefringence-dependent. With TE_0 as input mode, the *CT* between the adjacent waveguides sharply enlarged with the increase of n_{\perp, MoS_2} at $n_{\text{eff}}^{1, \text{TM}} = 1.53$, as depicted in Fig. 5(a). Specifically, when $n_{\perp, \text{MoS}_2} = 3.7$, *CT* is as high as -5.6 dB, and the corresponding *IL* exceeds 1 dB. When $W_1 = 455 \text{ nm}$, the increase of n_{\perp, MoS_2} has little effect on the transmission performance of the device [Fig. 5(b)]. This phenomenon can be attributed to the reduced optical birefringence (modal birefringence), which diminishes the phase mismatch between TE_0 in the thru waveguide and TE_0 in the cross waveguide. Notably, fixing $n_{\text{eff}}^{1, \text{TM}} = 1.53$ results in a significantly lower modal birefringence compared to fixing $W_1 = 455 \text{ nm}$ as shown in Fig. 4(a) inset. For instance, when the phase matching condition is satisfied at $n_{\text{eff}}^{1, \text{TM}} = 1.53$ and $n_{\perp, \text{MoS}_2} = 3.7$, the waveguide widths are optimized to $W_1 = 267 \text{ nm}$ and $W_2 = 250 \text{ nm}$, respectively. However, the corresponding modal birefringence is merely 0.36, which is far less than 1.4 observed at $n_{\perp, \text{MoS}_2} = 2.7$. Consequently, a portion of the optical energy couples into the adjacent waveguide, leading to an increase in insertion loss and mode crosstalk [Fig. 5(a) inset]. On the other hand, with TM_0 as input mode [Fig. 5(c, d)], regardless of the values of $n_{\text{eff}}^{1, \text{TM}} = 1.53$ or $W_1 = 455 \text{ nm}$, effective conversion of TM_0 to TE_0 can be achieved by satisfying the phase matching condition. However, the transmission coefficients noticeably decrease at low birefringence levels. Hence, the extreme birefringence of MoS_2 is crucial to realize an ultra-compact PSR with high transmission performance.

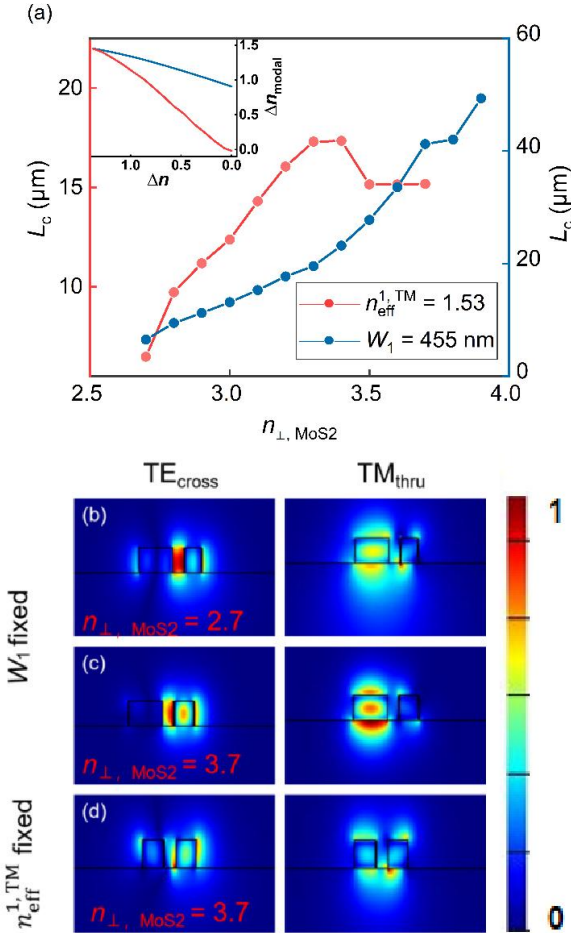


Fig. 4. Effect of the MoS_2 optical anisotropy on the coupling length of PSR. (a) Relationship between L_c and n_{\perp, MoS_2} , with fixing $n_{\text{eff}}^{1, \text{TM}} = 1.53$ or $W_1 = 455 \text{ nm}$. Inset: variation of the modal birefringence with n_{\perp, MoS_2} increase. Red: $n_{\text{eff}}^{1, \text{TM}} = 1.53$; Blue: $W_1 = 455 \text{ nm}$. Normalized electric field distributions of TE_{cross} and TM_{thru} in the ADC parallel straight waveguides with (b-c) $W_1 = 455 \text{ nm}$ and (d) $n_{\text{eff}}^{1, \text{TM}} = 1.53$.

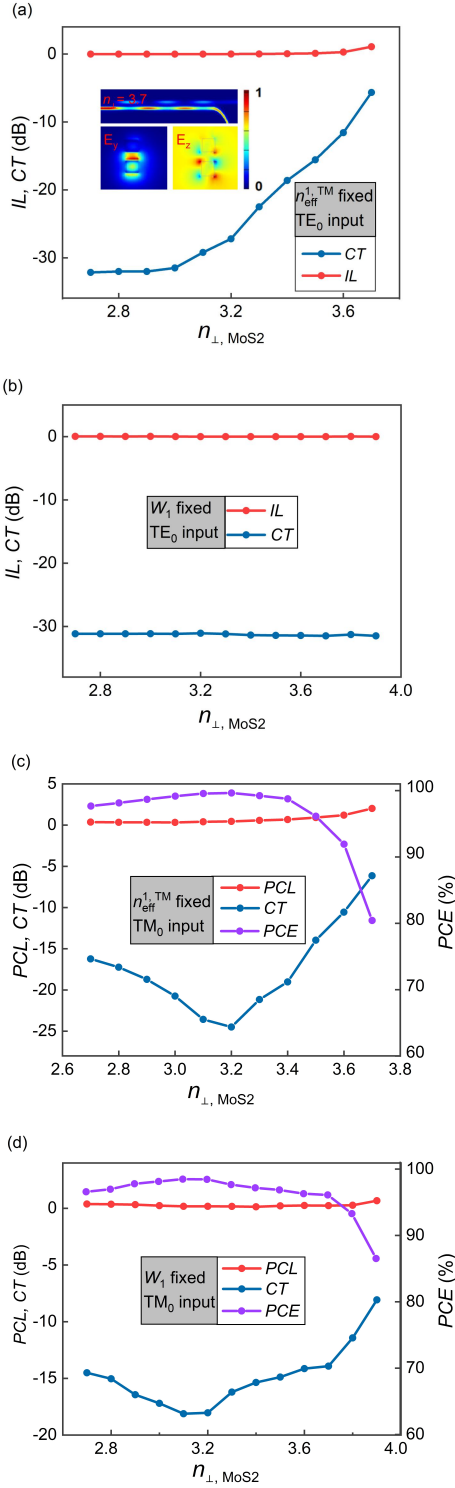


Fig. 5. Influence of MoS₂ birefringence on the transmission performance of PSR. *CT* and *IL* of the PSR with the variation of n_{\perp, MoS_2} in TE₀ input mode: (a) $n_{\text{eff}}^{1, \text{TM}} = 1.53$ Inset: when $n_{\text{eff}}^{1, \text{TM}} = 1.53$ and $n_{\perp, \text{MoS}_2} = 3.7$, the optical power distribution in the designed PSR, and the normalized electric field distribution (E_y and E_z) diagram of the cross-section of ADC. (b) $W_1 = 455$ nm. The *PCE*, *PCL* and *CT* of the PSR with the variation of n_{\perp, MoS_2} in TM₀ input mode: (c) $n_{\text{eff}}^{1, \text{TM}} = 1.53$. (d) $W_1 = 455$ nm. $W_g = 150$ nm.

IV. CONCLUSIONS

An ultra-compact and high-performance PSR based on the vdW-OI configuration is conceptually proposed and numerically demonstrated in this work. Due to the large modal birefringence between TE₀ and TM₀ modes in the thru

waveguide, the TE-TE coupling is suppressed while the TM-TE coupling can be of high efficiency. As a result, polarization conversion from TM₀ to TE₀ can be achieved within a coupling length as small as 6.0 μm with a high *PCE* of 96.97% and a low *PCL* of 0.38 dB ($\lambda = 1.55$ μm). At the same time, the *IL* and the *CT* for the TE₀ input mode are both extremely low (0.006 dB and -31.53 dB, respectively). We emphasize that both the ultra-compact size and the improved performances of our design stem from the giant birefringence exhibited by MoS₂. Therefore, our utilization of highly birefringent materials offers a promising strategy for density integration of polarization management devices based on vdW-OI configuration. Regarding practical fabrication, a device size less than 10 μm would greatly relax the requirement for large-sized single crystals thus mechanically exfoliated MoS₂ flakes are quite adequate.

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